NSN 5961-01-258-4759

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-258-4759 **Inclosure Material:** Metal **Overall Length:** 1.500 inches **Overall Height:** 0.350 inches **Overall Width:** 1.250 inches **Mounting Facility Quantity: Component Name And Quantity:** 4 semiconductor device diode **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 150.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 40.00 amperes forward current, average absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Test Data Document:** 97942-587r052 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 10 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**